DISCRETE SEMICONDUCTORS



Product specification

September 2018



BTA212 series B

GENERAL DESCRIPTION

Planar passivated high commutation triacs in a plastic envelope intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

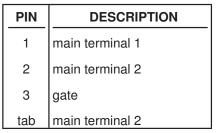
PINNING - TO220AB

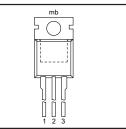
QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | MAX. | UNIT |
|---|---|--------------------------------|--------------------------------|-------------------------|-------------|
| V _{DRM} I _{T(RMS)} I _{TSM} | BTA212- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current | 500B 500 12 95 | 600B 600 12 95 | 800B 800 12 95 | V A A |

PIN CONFIGURATION

SYMBOL







LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT | |
|---|---|--|-------------|---------------------------------|---------------------------------|--------------------|------------------|
| V _{DRM} | Repetitive peak off-state voltages | | - | -500 500 ¹ | -600 600 ¹ | -800 800 | v |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 99 \degree C$ | - | | 12 | | A |
| I _{TSM} | Non-repetitive peak on-state current | full sine wave; $T_j = 25 \degree C$ prior to surge t = 20 ms | - | | 95 | | A |
| l²t dI _⊤ /dt | I ² t for fusing Repetitive rate of rise of on-state current after triggering | | - | | 105 45 100 | | Α A²s A/μs |
| I _{GM} V _{GM} P _{GM} P _{G(AV)} | Peak gate current Peak gate voltage Peak gate power Average gate power | over any 20 ms period | - - - | | 2 5 5 0.5 | | A V W W |
| $\begin{array}{c} T_{stg} \\ T_{j} \end{array}$ | Storage temperature Operating junction temperature | | -40 - | | 150 125 | | °C O |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|--|---|------|--------------|-----------------|-------------------|
| R _{th j-mb} R _{th j-a} | Thermal resistance junction to mounting base Thermal resistance junction to ambient | full cycle half cycle in free air | | - - 60 | 1.5 2.0 - | K/W K/W K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|----------------------------------|-----------------------------------|--|--------|--------|------|------|------|
| I _{GT} | Gate trigger current ² | $V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$ | | | | | |
| ai | | | T2+ G+ | 2 | 18 | 50 | mA |
| | | | T2+ G- | 2 2 | 21 | 50 | mA |
| | | | T2- G- | 2 | 34 | 50 | mA |
| IL . | Latching current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | | | | |
| | - | - | T2+ G+ | - | 31 | 60 | mA |
| | | | T2+ G- | - | 34 | 90 | mA |
| | | | T2- G- | - | 30 | 60 | mA |
| I _H | Holding current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | - | 31 | 60 | mA |
| I _H V _T | On-state voltage | $I_{T} = 17 \text{ A}$ | | - | 1.3 | 1.6 | V |
| V _{GT} | Gate trigger voltage | $\dot{V}_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ | | - | 0.7 | 1.5 | V |
| | | $V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm L} = 1000 \text{ V};$ | 125 °C | 0.25 | 0.4 | - | V |
| I _D | Off-state leakage current | $V_{D}^{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 100 \text{ V}_{D} = V_{DRM(max)}; T_{j} = 125 \text{ °C}$ | | - | 0.1 | 0.5 | mA |

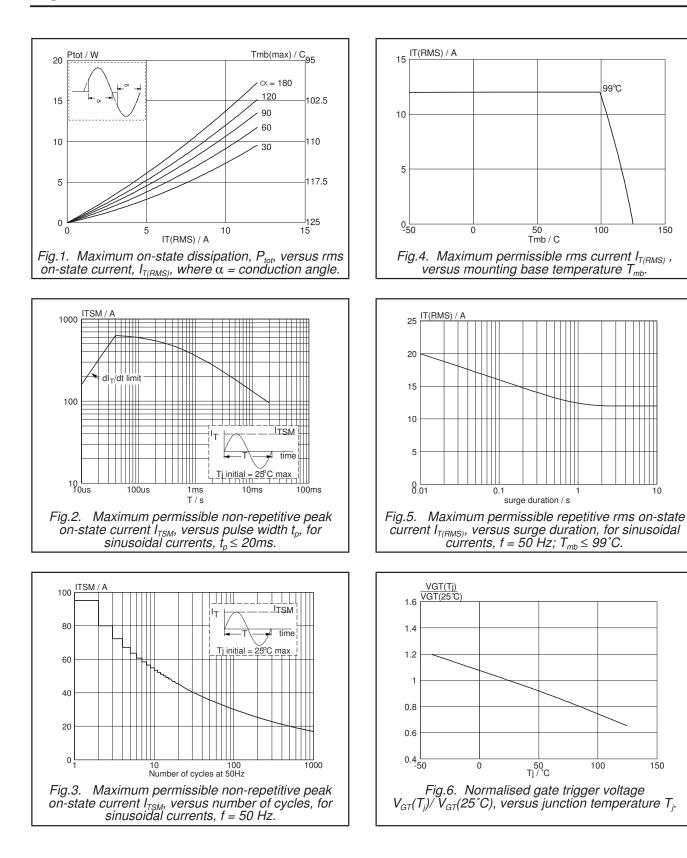
DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

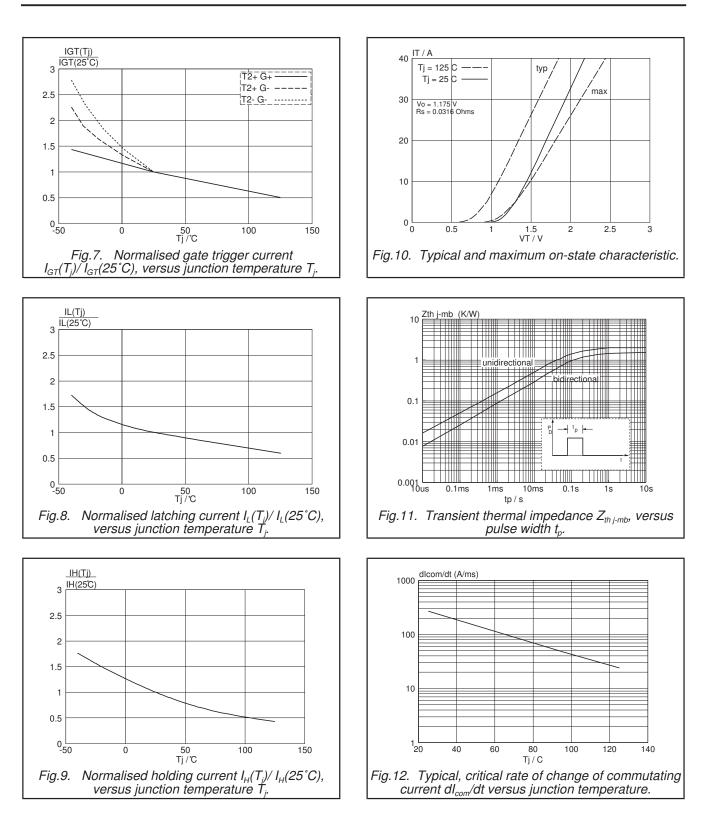
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------------------|---|--|------|------|------|------|
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; gate open circuit | 1000 | 4000 | - | V/µs |
| dI _{com} /dt | Critical rate of change of commutating current | $V_{DM} = 400 \text{ V}; T_j = 125 \text{ °C}; I_{T(RMS)} = 12 \text{ A};$ without snubber; gate open circuit | - | 24 | - | A/ms |
| t _{gt} | Gate controlled turn-on time | $I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu \text{s}$ | - | 2 | - | μs |

² Device does not trigger in the T2-, G+ quadrant.

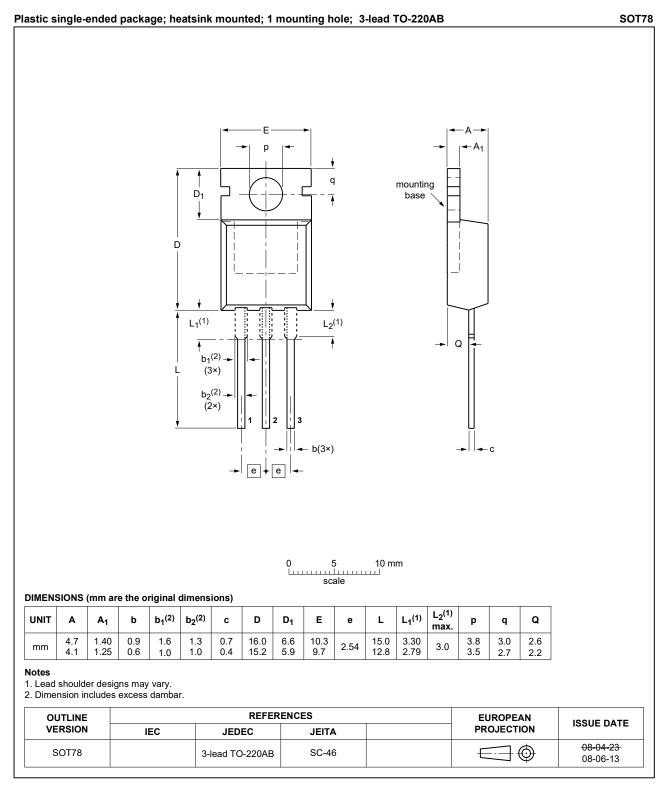
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MECHANICAL DATA



Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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